INTEGRATED CIRCUITS

DATA SHEET

74ALVT162244

2.5V/3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

Product specification Supersedes data of 1998 Feb 13 IC23 Data Handbook





2.5V/3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

74ALVT162244

FEATURES

- 16-bit bus interface
- 3-State buffers
- 5V I/O compatibile
- Output capability: +12mA/-12mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- \bullet Outputs include series resistance of 30Ω making external terminating resistors unnecessary
- Power-up 3-State
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

DESCRIPTION

The 74ALVT162244 is a high-performance BiCMOS product designed for $\rm V_{CC}$ operation at 2.5V or 3.3V with I/O compatibility up to 5V.

The 74ALVT162244 is designed with 30Ω series resistance in both the High and Low states of the output. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus receivers/transmitters.

This device is a 16-bit buffer and line driver featuring non-inverting 3-State bus outputs. The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer.

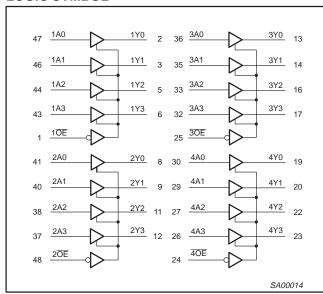
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYPI	UNIT		
STWIBOL	PARAMETER	T _{amb} = 25°C	2.5V	3.3V	ONIT	
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	C _L = 50pF	2.7 2.3	2.2 2.2	ns	
C _{IN}	Input capacitance DIR, OE	$V_I = 0V \text{ or } V_{CC}$	3	3	pF	
C _{Out}	Output capacitance	$V_{I/O} = 0V \text{ or } V_{CC}$	9	9	pF	
I _{CCZ}	Total supply current	Outputs disabled	40	70	μΑ	

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	-40°C to +85°C	74ALVT162244 DL	AV162244 DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74ALVT162244 DGG	AV162244 DGG	SOT362-1

LOGIC SYMBOL



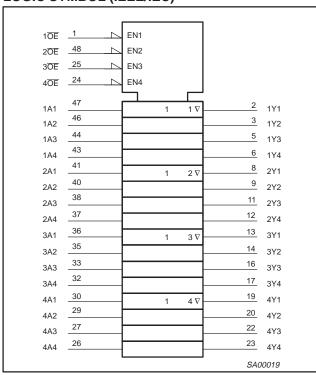
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
47, 46, 44, 43 41, 40, 38, 37 36, 35, 33, 32 30, 29, 27, 26	1A0 - 1A3, 2A0 - 2A3, 3A0 - 3A3, 4A0 - 4A3	Data inputs
2, 3, 5, 6 8, 9, 11, 12 13, 14, 16, 17 19, 20, 22, 23	1Y0 - 1Y3, 2Y0 - 2Y3, 3Y0 - 3Y3, 4Y0 - 4Y3	Data outputs
1, 48 25, 24	1 OE , 2 OE , 3 OE , 4 OE	Output enables
4, 10, 15, 21 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V _{CC}	Positive supply voltage

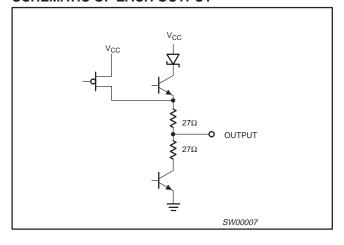
2.5V/3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

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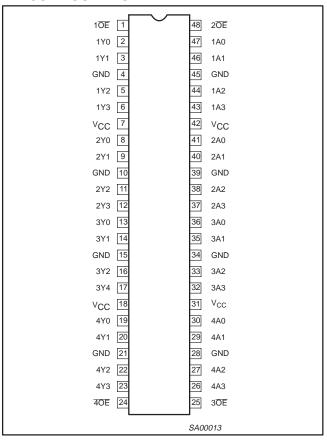
LOGIC SYMBOL (IEEE/IEC)



SCHEMATIC OF EACH OUTPUT



PIN CONFIGURATION



FUNCTION TABLE

INPUTS		OUTPUTS
nOE	nAx	nYx
L	L	L
L	Н	Н
Н	Х	Z

H = High voltage level

L = Low voltage level

X = Don't care

Z = High Impedance "off" state

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ABSOLUTE MAXIMUM RATINGS1, 2

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V _I < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
lok	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
	DC output current	Output in Low state	128	A
lout		Output in High state	-64	mA
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	2.5V RANGE LIMITS		3.3V RANGE LIMITS		UNIT	
STWIBOL	TANAMETEN	MIN	MAX	MIN	MAX	ONIT	
V _{CC}	DC supply voltage	2.3	2.7	3.0	3.6	V	
VI	Input voltage	0	5.5	0	5.5	V	
V _{IH}	High-level input voltage	1.7		2.0		V	
V _{IL}	Input voltage		0.7		0.8	V	
I _{OH}	High-level output current		-8		-12	mA	
I _{OL}	Low-level output current		12		12	mA	
Δt/Δν	Input transition rise or fall rate; Outputs enabled		10		10	ns/V	
T _{amb}	Operating free-air temperature range	-40	+85	-40	+85	°C	

Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
absolute-maximum-rated conditions for extended periods may affect device reliability.

^{2.} The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

^{3.} The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

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DC ELECTRICAL CHARACTERISTICS (3.3V \pm 0.3V RANGE)

		TEST CONDITIONS					
SYMBOL	PARAMETER			TEST CONDITIONS Temp = -40°C to +85		+85°C	UNIT
				MIN	TYP ¹	MAX	1
V _{IK}	Input clamp voltage	$V_{CC} = 3.0V; I_{IK} = -18mA$			-0.85	-1.2	V
V _{OH}	High-level output voltage	$V_{CC} = 3.0V; I_{OH} = -12mA$		2.0	2.5		V
V _{OL}	Low-level output voltage	$V_{CC} = 3.0V; I_{OL} = 12mA$			0.5	0.8	1 °
		$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND	Control pins		0.1	±1	
ı,	Input leakage current	$V_{CC} = 0 \text{ or } 3.6V; V_I = 5.5V$			01.	10	μА
ŧι	Imput leakage current	$V_{CC} = 3.6V; V_I = V_{CC}$	Data pins ⁴		0.5	1	μΑ
		$V_{CC} = 3.6V; V_I = 0V$	Data pilis		0.1	-5	
I _{OFF}	Off current	$V_{CC} = 0V; V_{I} \text{ or } V_{O} = 0 \text{ to } 4.5V$			0.1	±100	μΑ
	Bus Hold current	V _{CC} = 3V; V _I = 0.8V		75	130		
I _{HOLD}		$V_{CC} = 3V; V_I = 2.0V$		-75	-140		μΑ
	Data inputs ⁶	V _{CC} = 0V to 3.6V; V _{CC} = 3.6V		±500			1
I _{EX}	Current into an output in the High state when V _O > V _{CC}	V _O = 5.5V; V _{CC} = 3.0V			10	125	μА
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \le 1.2V$; $V_O = 0.5V$ to V_{CC} ; $V_I = GNDOE/OE = Don't$ care	or V _{CC}		1	±100	μА
l _{OZH}	3-State output High current	$V_{CC} = 3.6V; V_{O} = 3.0V; V_{I} = V_{IL} \text{ or } V_{IH}$			0.5	5	μА
I _{OZL}	3-State output Low current	$V_{CC} = 3.6V; V_{O} = 0.5V; V_{I} = V_{IL} \text{ or } V_{IH}$			0.5	- 5	μА
I _{CCH}		$V_{CC} = 3.6V$; Outputs High, $V_I = GND$ or V_{CC} , $I_{O} = 0$			0.05	0.1	
I _{CCL}	Quiescent supply current	$V_{CC} = 3.6V$; Outputs Low, $V_I = GND$ or V_{CC} , $I_{O} = 0$			3.7	5.0	mA
I _{CCZ}	1	$V_{CC} = 3.6V$; Outputs Disabled; $V_I = GND$ or V_{CC} , $I_{O} = 0^5$			0.06	0.1	1
Δl _{CC}	Additional supply current per input pin ²	V_{CC} = 3V to 3.6V; One input at V_{CC} -0.6' Other inputs at V_{CC} or GND	V,		0.05	0.4	mA

NOTES:

- 1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^{\circ}C$.
- This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
 This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C only.

- 4. Unused pins at V_{CC} or GND.
 5. I_{CCZ} is measured with outputs pulled up to V_{CC} or pulled down to ground.
 6. This is the bus hold overdrive current required to force the input to the opposite logic state.

AC CHARACTERISTICS (3.3V \pm 0.3V RANGE)

GND = 0V; $t_R = t_F = 2.5 \text{ns}$; $C_L = 50 \text{pF}$; $R_L = 500 \Omega$; $T_{amb} = -40 ^{\circ} \text{C}$ to +85 $^{\circ} \text{C}$.

SYMBOL	PARAMETER	WAVEFORM	V _C	UNIT		
			MIN	TYP ¹	MAX	
t _{PLH} t _{PHL}	Propagation delay nAx to nBx or nBx to nAx	1	1.0 1.0	2.2 2.2	3.3 3.3	ns
^t PZH t _{PZL}	Output enable time to High and Low level	2	1.5 1.5	3.2 2.4	4.9 3.7	ns
t _{PHZ}	Output disable time from High and Low Level	2	1.5 1.5	3.1 2.5	4.7 4.1	ns

1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

2.5V/3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

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DC ELECTRICAL CHARACTERISTICS (2.5V \pm 0.2V RANGE)

		TEST CONDITIONS		LIMITS			
SYMBOL	PARAMETER			Temp = -40°C to +		+85°C	UNIT
				MIN	TYP ¹	MAX	
V _{IK}	Input clamp voltage	$V_{CC} = 2.3V; I_{IK} = -18mA$			-0.85	-1.2	V
V _{OH}	High-level output voltage	$V_{CC} = 2.3V; I_{OH} = -8mA$		1.7			V
V _{OL}	Low-level output voltage	$V_{CC} = 2.3V; I_{OL} = 12mA$			0.6	0.7	1 °
		$V_{CC} = 2.7V$; $V_I = V_{CC}$ or GND	Control pins		0.1	±1	
ı.	Input leakage current	V _{CC} = 0 or 2.7V; V _I = 5.5V			0.1	10	μА
Η	Imput leakage current	$V_{CC} = 2.7V; V_I = V_{CC}$	Data pins ⁴		0.1	1	μΑ
		$V_{CC} = 2.7V; V_I = 0$	Data pilis		0.1	-5	1 1
I _{OFF}	Off current	$V_{CC} = 0V$; V_{I} or $V_{O} = 0$ to 4.5V			0.1	±100	μΑ
	Bus Hold current	$V_{CC} = 2.3V; V_I = 0.7V$			115		
HOLD	Data inputs ⁶	V _{CC} = 2.3V; V _I = 1.7V			-10		μΑ
I _{EX}	Current into an output in the High state when V _O > V _{CC}	V _O = 5.5V; V _{CC} = 2.3V			10	125	μА
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \le 1.2V$; $V_O = 0.5V$ to V_{CC} ; $V_I = GNE$ OE/OE = Don't care	or V _{CC} ;		1	±100	μА
I _{OZH}	3-State output High current	$V_{CC} = 2.7V$; $V_{O} = 2.3V$; $V_{I} = V_{IL}$ or V_{IH}			0.5	5	μΑ
I _{OZL}	3-State output Low current	$V_{CC} = 2.7V$; $V_{O} = 0.5V$; $V_{I} = V_{IL}$ or V_{IH}			0.5	- 5	μА
Іссн		$V_{CC} = 2.7V$; Outputs High, $V_I = GND$ or V_{CC} , $I_O = 0$			0.04	0.1	
I _{CCL}	Quiescent supply current	$V_{CC} = 2.7V$; Outputs Low, $V_I = GND$ or V_{CC} , $I_O = 0$			2.5	4.5	mΑ
I _{CCZ}	1	$V_{CC} = 2.7V$; Outputs Disabled; $V_I = GND$ or V_{CC} , $I_O = 0^5$			0.04	0.1	1
Δl _{CC}	Additional supply current per input pin ²	V_{CC} = 2.3V to 2.7V; One input at V_{CC} -0 Other inputs at V_{CC} or GND	.6V,		0.04	0.4	mA

- All typical values are at V_{CC} = 2.5V and T_{amb} = 25°C.
 This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
 This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 2.5V ± 0.2V a transition time of 100 μ sec is permitted. This parameter is valid for $T_{amb} = 25$ °C only.
- 4. Unused pins at V_{CC} or GND.
- 5. I_{CCZ} is measured with outputs pulled up to V_{CC} or pulled down to ground.
- 6. Not guaranteed.

AC CHARACTERISTICS (2.5V \pm 0.2V RANGE)

GND = 0V; $t_R = t_F$ = 2.5ns; C_L = 50pF; R_L = 500 Ω ; T_{amb} = -40°C to +85°C.

		PARAMETER WAVEFORM				
SYMBOL	PARAMETER		V _C	UNIT		
			MIN	TYP ¹	MAX	
t _{PLH} t _{PHL}	Propagation delay nAx to nBx or nBx to nAx	1	1.5 1.5	2.7 2.3	4.2 3.7	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	2.0 2.0	4.4 3.0	6.8 5.1	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low Level	2	1.0 1.0	2.8 2.0	4.6 3.3	ns

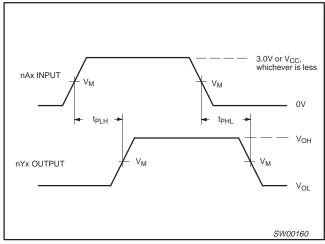
1. All typical values are at V_{CC} = 2.5V and T_{amb} = 25°C.

2.5V/3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

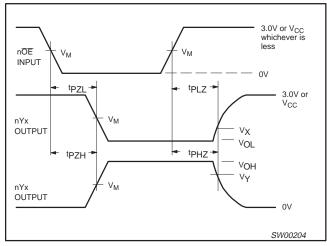
74ALVT162244

AC WAVEFORMS

 V_M = 1.5V at V_{CC} ≥ 3.0V; V_M = V_{CC} /2 at V_{CC} ≤ 2.7V V_X = V_{OL} + 0.3V at V_{CC} ≥ 3.0V; V_X = V_{OL} + 0.15V at V_{CC} ≤ 2.7V V_Y = V_{OH} - 0.3V at V_{CC} ≥ 3.0V; V_Y = V_{OH} - 0.15V at V_{CC} ≤ 2.7V

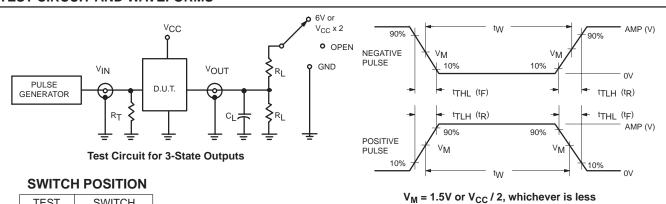


Waveform 1. Input (nAx) to Output (nYx) Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times

TEST CIRCUIT AND WAVEFORMS



TEST	SWITCH		
t _{PHZ} /t _{PZH}	GND		
t _{PLZ} /t _{PZL}	6V or V _{CC} x 2		
t _{PLH} /t _{PHL}	open		

DEFINITIONS

 R_L = Load resistor; see AC CHARACTERISTICS for value.

C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

 R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

FARMILY	INPUT PULSE REQUIREMENTS						
FAMILY	Amplitude	Rep. Rate	t _W	t _R	t _F		
74ALVT16	3.0V or V _{CC} whichever is less	≤10MHz	500ns	≤2.5ns	≤2.5ns		

Input Pulse Definition

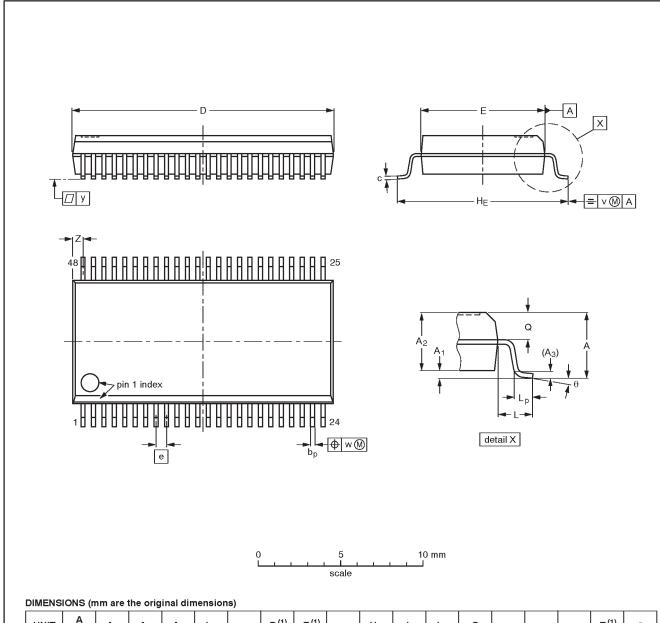
SW00162

2.5V/3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

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SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1



UNIT	A max.	Α1	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	16.00 15.75	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

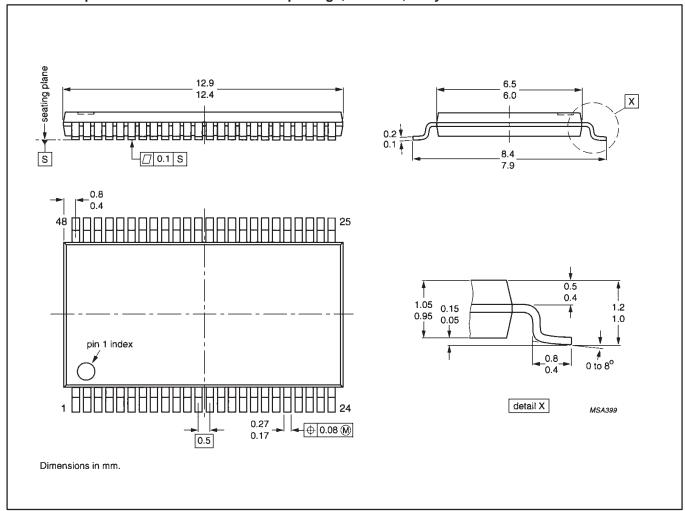
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1990E DATE	
SOT370-1		MO-118AA				93-11-02 95-02-04	

2.5V/3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

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TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1mm





2.5V/3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

^[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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